# For Fuji Electric FGW50N60HC

**Discrete IGBT** 

# Discrete IGBT (High-Speed V series) 600V / 50A

#### Features

Low power loss Low switching surge and noise High reliability, high ruggedness (RBSOA, SCSOA etc.)

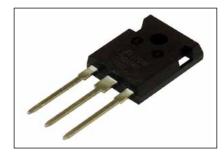
#### Applications

Uninterruptible power supply Power coditionner Power factor correction circuit

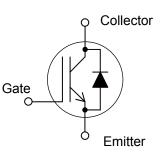
## Maximum Ratings and Characteristics

• Absolute Maximum Ratings (at Tj=25°C unless otherwise specified)

Items	Symbols	Characteristics	Units	Remarks
Collector-Emitter Voltage	VCES	600	V	
Gate-Emitter Voltage	VGES	±20	V	
DC Collector Current	LC@25	95	Α	Tc=25°C,Tj=150°C
	C@100	50	Α	Tc=100°C,Tj=150°C
Pulsed Collector Current	ICP	150	Α	Note *1
Turn-Off Safe Operating Area	-	150	Α	Vce≤600V,Tj≤175°C
Diode Forward Current	F@25	76	Α	
	F@100	50	Α	
Diode Pulsed Current	IFP	150	Α	Note *1
Short Circuit Withstand Time	tsc	5	μs	V <sub>cc</sub> ≤300V,V <sub>GE</sub> =12V
				Tj≤150°C
IGBT Max. Power Dissipation	PD_IGBT	360	w	Tc=25°C
FWD Max. Power Dissipation	PD_FWD	190	vv	Tc=25°C
<b>Operating Junction Temperature</b>	Tj	-40 ~ +175	°C	
Storage Temperature	Tstg	-55 ~ +175	°C	



#### Equivalent circuit



Note \*1 : Pulse width limited by Tjmax.

#### • Electrical characteristics (at T<sub>j</sub>= 25°C unless otherwise specified)

Description	Symbolo	Symbols Conditions		Characteristics			Units
Description	Symbols			min.	typ.	max.	Units
Collector-Emitter Breakdown Voltage	V <sub>(BR)CES</sub>	Ic = 250µA, V <sub>GE</sub> = 0V		600	-	-	V
Zero Gate Voltage Collector Current	ICES	V <sub>CE</sub> = 600V. V <sub>GE</sub> = 0V	Tj=25°C	-	-	250	μA
ŭ		,	Tj=175°C	-	-	10	mA
Gate-Emitter Leakage Current	IGES	$V_{CE} = 0V, V_{GE} = \pm 20V$		-	-	200	nA
Gate-Emitter Threshold Voltage	VGE (th)	V <sub>CE</sub> = +20V, I <sub>C</sub> = 50mA		4.0	5.0	6.0	V
Collector-Emitter Saturation Voltage	V <sub>CE (sat)</sub>	$V_{GE}$ = +15V, I <sub>c</sub> = 50A	Tj=25°C Tj=175°C	-	1.50 1.80	1.95	V
Input Capacitance	Cies	V <sub>CE</sub> =25V	1.,	-	4320	-	pF
Output Capacitance	Coes	V <sub>GE</sub> =0V		-	210	-	
Reverse Transfer Capacitance	Cres	f=1MHz		-	160	-	
Gate Charge	QG	V <sub>cc</sub> = 400V I <sub>c</sub> = 50A V <sub>GE</sub> = 15V		-	305	-	nC
Turn-On Delay Time	t <sub>d(on)</sub>	$T_{i} = 25^{\circ}C$ $V_{cc} = 400V$ $I_{c} = 50A$		-	33	-	ns
Rise Time	t			-	70	-	
Turn-Off Delay Time	t <sub>d(off)</sub>			-	310	-	
Fall Time	tr	V <sub>GE</sub> = 15V		-	60	-	
Turn-On Energy	Eon	$R_{G} = 10\Omega$		-	1.5	-	
Turn-Off Energy	Eoff	L = 500µH Energy loss include "tail" and FWD reverse recovery.		-	1.7	-	mJ
Turn-On Delay Time	t <sub>d(on)</sub>	$T_{j} = 175^{\circ}C$		-	30	-	
Rise Time	t	$V_{cc} = 400V$ $I_c = 50A$ $V_{GE} = 15V$		-	62	-	
Turn-Off Delay Time	t <sub>d(off)</sub>			-	335	-	ns
Fall Time	tr			-	72	-	
Turn-On Energy	Eon	$R_{G} = 10\Omega$		-	2.2	-	
Turn-Off Energy	Eoff	L = 500µH Energy loss include "tail" and FWD reverse recovery.			2.2	-	mJ

#### • FWD Characteristics

Description	Symbol	Conditions	Canditiana		Characteristics		
Sym		mbol Conditions		min.	typ.	max.	Unit
	VF	I==50A	Tj=25°C	-	2.25	2.95	V
Forward Voltage Drop	VF	I⊧=50A	Tj=175°C	-	1.65	-	V
Diode Reverse Recovery Time	trr1	V <sub>cc</sub> =30V,I <sub>F</sub> = 5A -di/dt=200A/µs		-	30	41	ns
Diode Reverse Recovery Time	trr2	V <sub>cc</sub> =400V I⊧=50A			0.04	-	μs
Diode Reverse Recovery Charge	Qrr	-di⊧/dt=200A/µs Tj=25°C		-	0.07	-	μC
Diode Reverse Recovery Time	trr2	V <sub>cc</sub> =400V I⊧=50A		-	0.16	-	μs
Diode Reverse Recovery Charge	Qrr	-di⊧/dt=200A/µs Tյ=175°C		-	1.00	-	μC

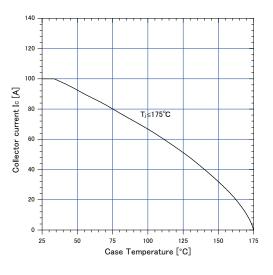
#### Thermal Resistance

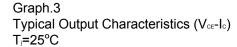
Description Symbols	Symbols	Conditions	Characteristics			Units
	Symbols		min.	typ.	max.	Units
Thermal Resistance, Junction-Ambient	Rth(j-a)	-	-	-	50	
Thermal Resistance, IGBT Junction to Case	Rth(j-c)_IGBT	-	-	-	0.417	°C/W
Thermal Resistance, FWD Junction to Case	Rth(j-c)_FWD	-	-	-	0.781	

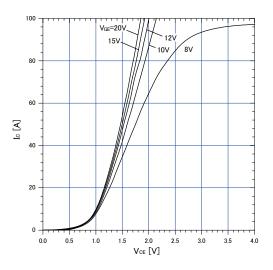
#### Characteristics (Representative)

Graph.1 DC Collector Current vs T<sub>c</sub>

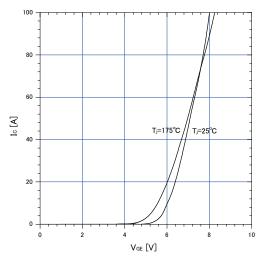
V<sub>GE</sub>≥+15V, T<sub>i</sub>≤175°C

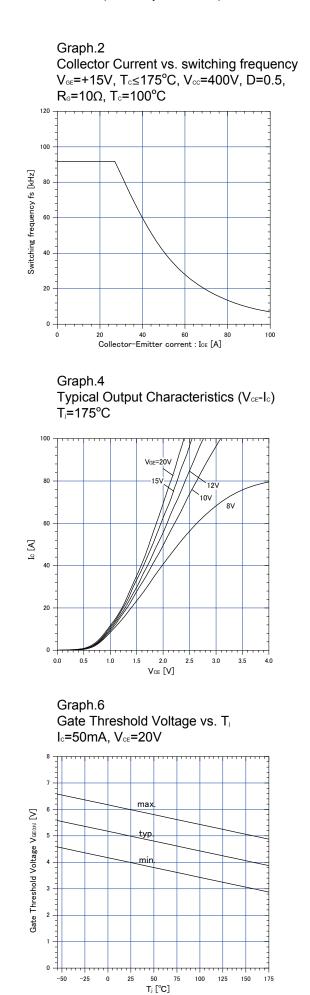




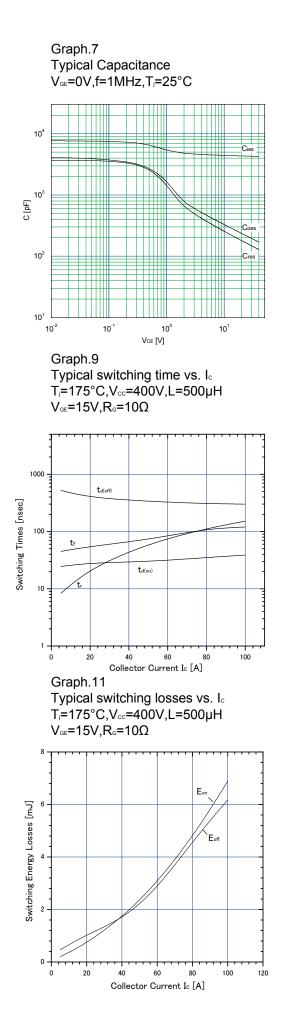


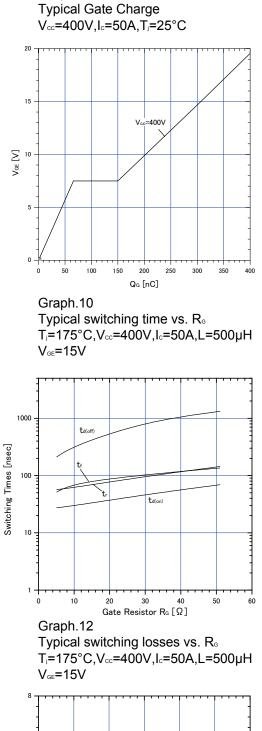


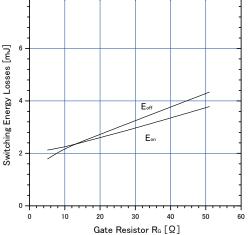




Graph.8



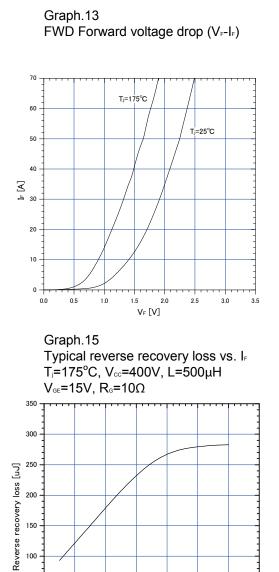


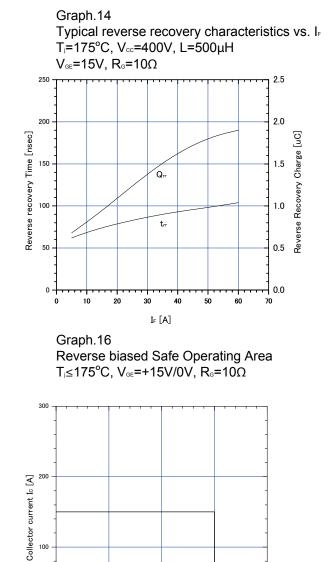


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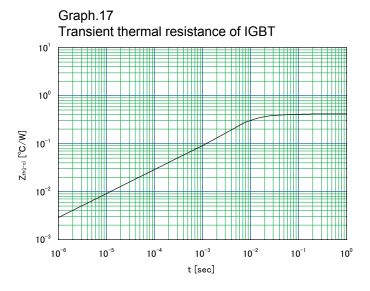
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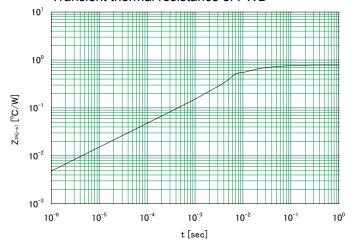




 $Collector-Emitter \ voltage: V_{CE} \ [V]$ 







## Outline Drawings, mm

Outview : TO-247 Package	
$\begin{array}{c} \begin{array}{c} 15.9 \pm 0.15 \\ \hline 2.23 \pm 0.19 \\ \hline 15.9 \pm 0.15 \\ \hline 2.23 \pm 0.19 \\ \hline 15.9 \pm 0.15 \\ \hline 10.19 \\ \hline 10.19 \\ \hline 11.1 \\ \hline 10.13 \\ \hline 1.2 \pm 0.13 \\ \hline 1.2 \pm 0.13 \\ \hline 5.45 \pm 0.254 \\ \end{array}$	$5.03 \pm 0.15$ $1.98 \pm 0.15$ $14.02 \pm 0.13$ $14.02 \pm 0.13$ $14.02 \pm 0.13$ $14.02 \pm 0.13$ $1.98 \pm 0.15$ $14.02 \pm 0.13$ $1.98 \pm 0.15$ $5.03 \pm 0.15$
	CONNECTION ① GATE
	2 COLLECTOR
	3 EMITTER
1 2 3	DIMENSIONS ARE IN MILLIMETERS.

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